

Product Summary

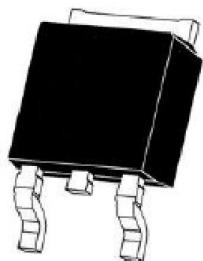
$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
600V	2.5Ω@10V	5A

Feature

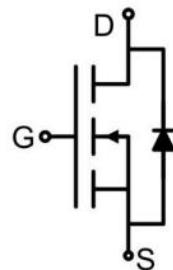
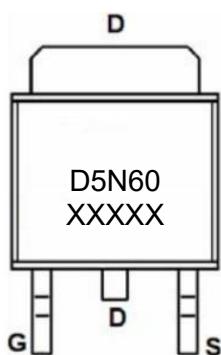
- Fast switching capability
- Improved dv/dt capability, high ruggedness

Application

- High Speed Switching Applications
- Power Supplies and Adaptors

Package

TO-252AB

Circuit diagram**Marking**

Absolute maximum ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	600	V
Gate-Source Voltage	V_{GS}	± 30	V
Continuous Drain Current($T_C = 25^\circ\text{C}$)	I_D	5	A
Continuous Drain Current($T_C = 100^\circ\text{C}$)	$I_D(100^\circ\text{C})$	3.2	A
Pulsed Drain Current ¹⁾	I_{DM}	20	A
Power Dissipation($T_C = 25^\circ\text{C}$)	P_D	35	W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	4	$^\circ\text{C}/\text{W}$
Single pulse avalanche energy ²⁾	E_{AS}	50	mJ
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Electrical characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	600			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 600\text{V}, V_{GS} = 0\text{V}$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$			± 100	nA
Gate threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	2.0		4.0	V
Drain-source on-resistance	$R_{DS(\text{on})}$	$V_{GS} = 10\text{V}, I_D = 2\text{A}$		2.04	2.5	Ω
Transconductance	g_{FS}	$V_{DS} = 15\text{V}, I_D = 2\text{A}$		3.1		S
Dynamic characteristics⁵⁾						
Input Capacitance	C_{iss}	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$		564		pF
Output Capacitance	C_{oss}			66		
Reverse Transfer Capacitance	C_{rss}			12		
Gate Resistance	R_g			2.3		Ω
Total Gate Charge ³⁾	Q_g	$V_{DS} = 480\text{V}, V_{GS} = 10\text{V}, I_D = 5\text{A}, I_G = 1\text{mA}$ ^{3,4)}		13		nC
Gate-Source Charge	Q_{gs}			4.1		
Gate-Drain Charge	Q_{gd}			4.9		
Turn-on delay time ³⁾	$t_{d(on)}$	$V_{DS} = 300\text{V}, V_{GS} = 10\text{V}, I_D = 5\text{A}, R_G = 25\Omega$ ^{3,4)}		31		nS
Turn-on rise time	t_r			76		
Turn-off delay time	$t_{d(off)}$			61		
Turn-off fall time	t_f			56		
Source-Drain Diode characteristics						
Diode Forward voltage ³⁾	V_{SD}	$V_{GS} = 0\text{V}, I_{SD} = 5\text{A}$			1.4	V
Diode Forward Current	I_S				5	A
Reverse Recovery Time ³⁾	t_{rr}	$I_F = 5\text{A}, di/dt = 100\text{A}/\mu\text{s}$		250		nS
Reverse Recovery Charge	Q_{rr}			4.5		μC

Notes:

1) Repetitive Rating: Pulse width limited by maximum junction temperature.

2) $L = 25\text{mH}, I_{AS} = 2\text{A}, V_{DD} = 50\text{V}, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$.

3) Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.

4) Essentially independent of operating temperature.

5) Guaranteed by design, not subject to production.



Typical Characteristics

Fig.1 Output characteristics

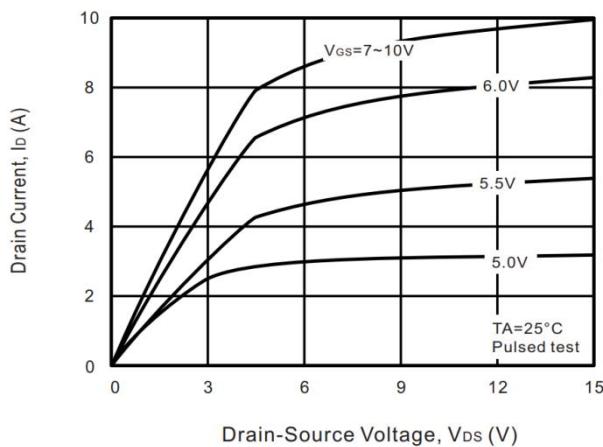


Fig.2 Power Dissipation

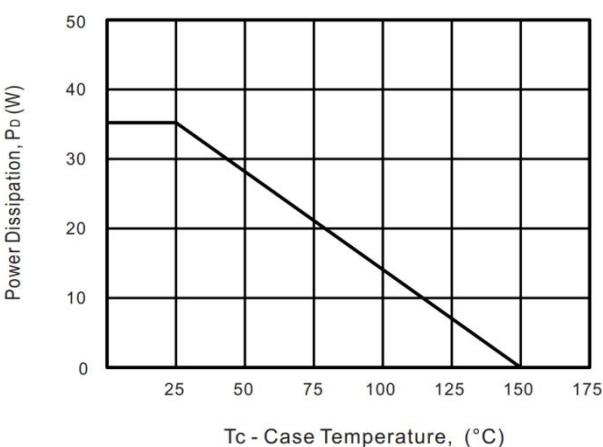


Fig.3 Drain Current Derating

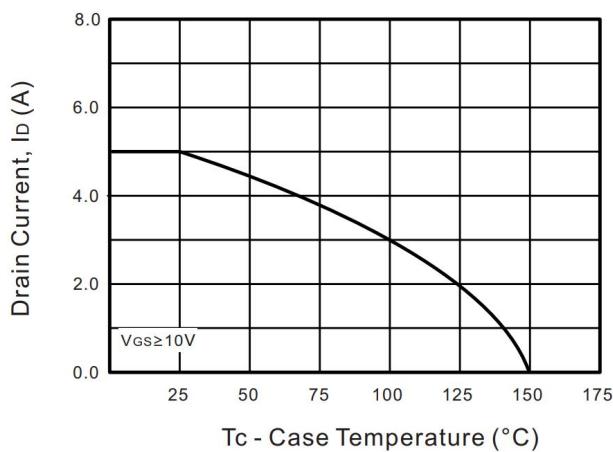


Fig.4 Drain-Source On-Resistance vs. Drain Current

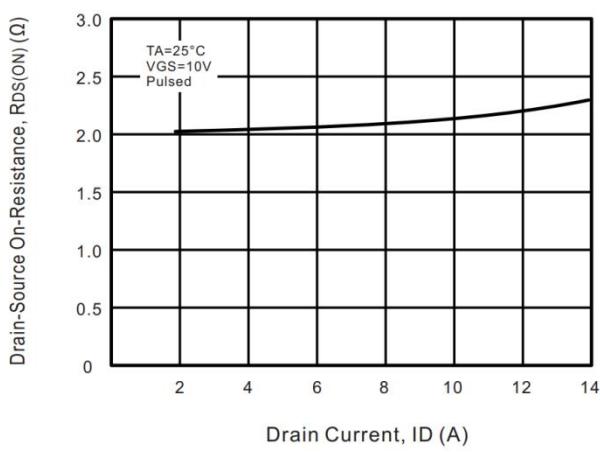


Fig.5 Gate Threshold Voltage vs. Junction Temperature

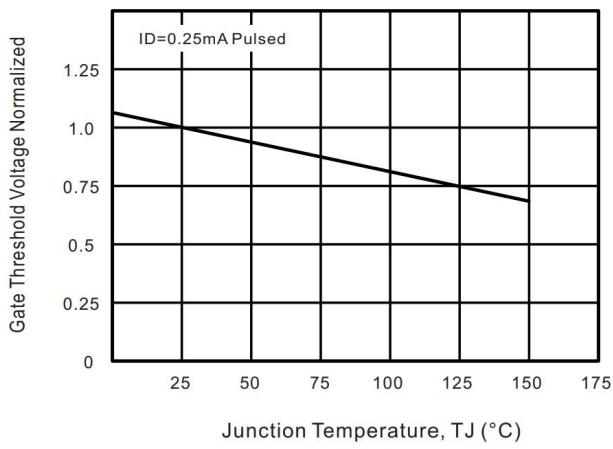
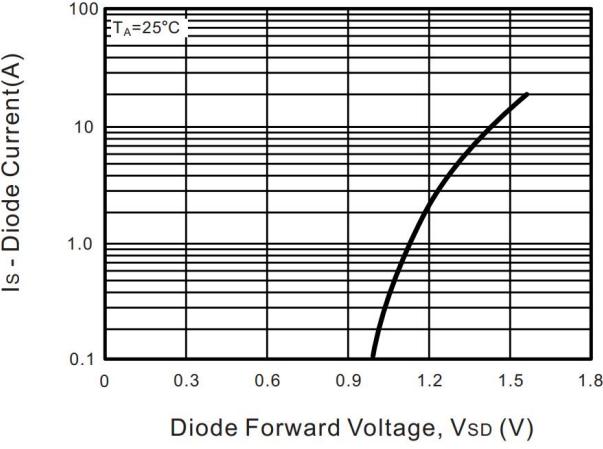


Fig.6 Body-diode Forward Characteristics



Typical Characteristics

Fig.7 Drain-Source On-Resistance vs. Junction Temperature

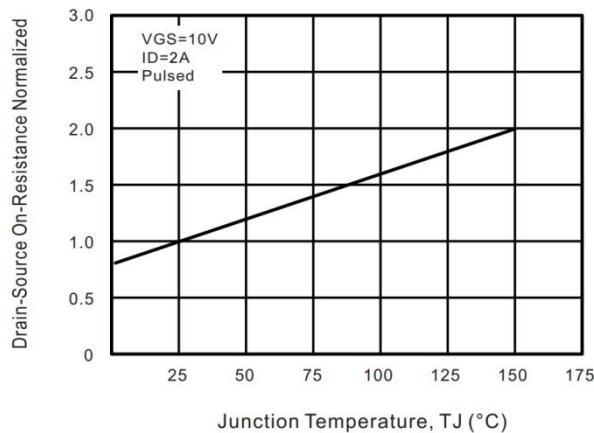


Fig.8 Breakdown Voltage vs. Junction Temperature

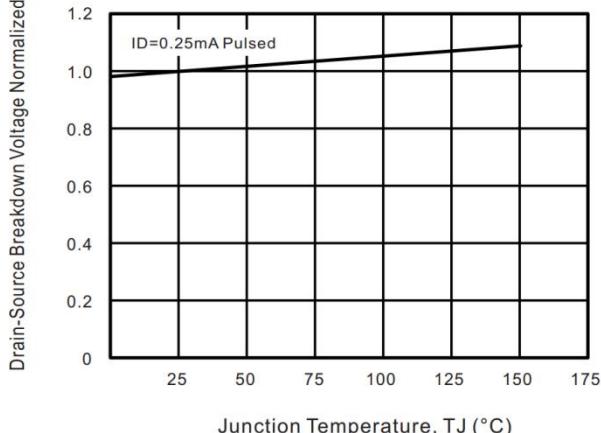


Fig.9 Capacitance Characteristics

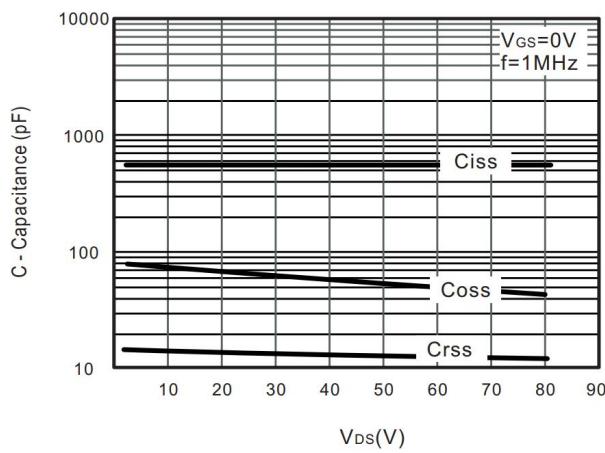


Fig.10 Gate Charge Characteristics

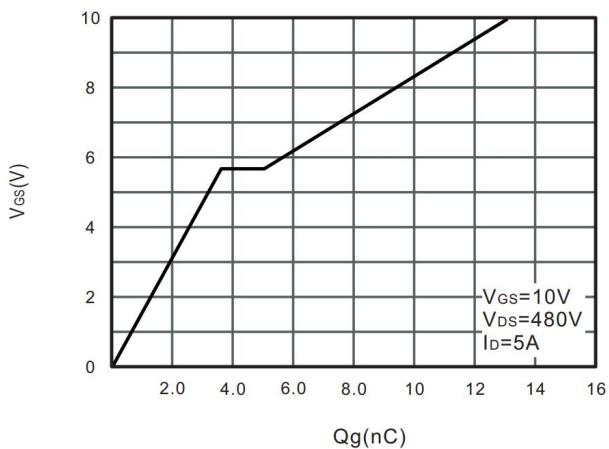


Fig.11 Safe Operating Area

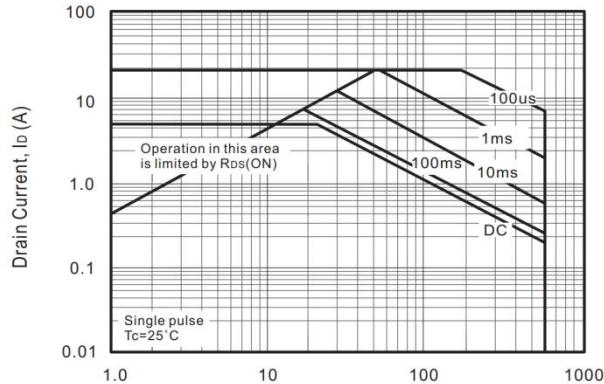
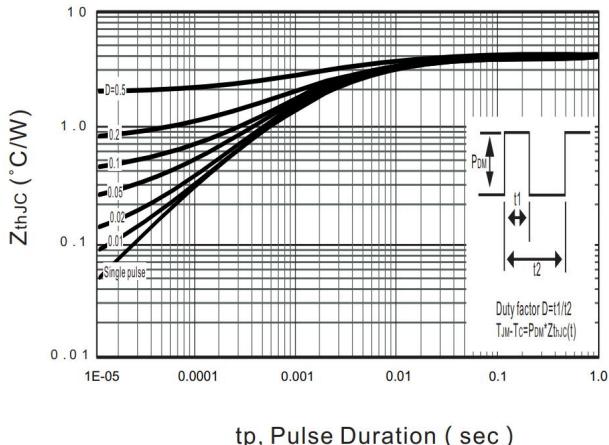
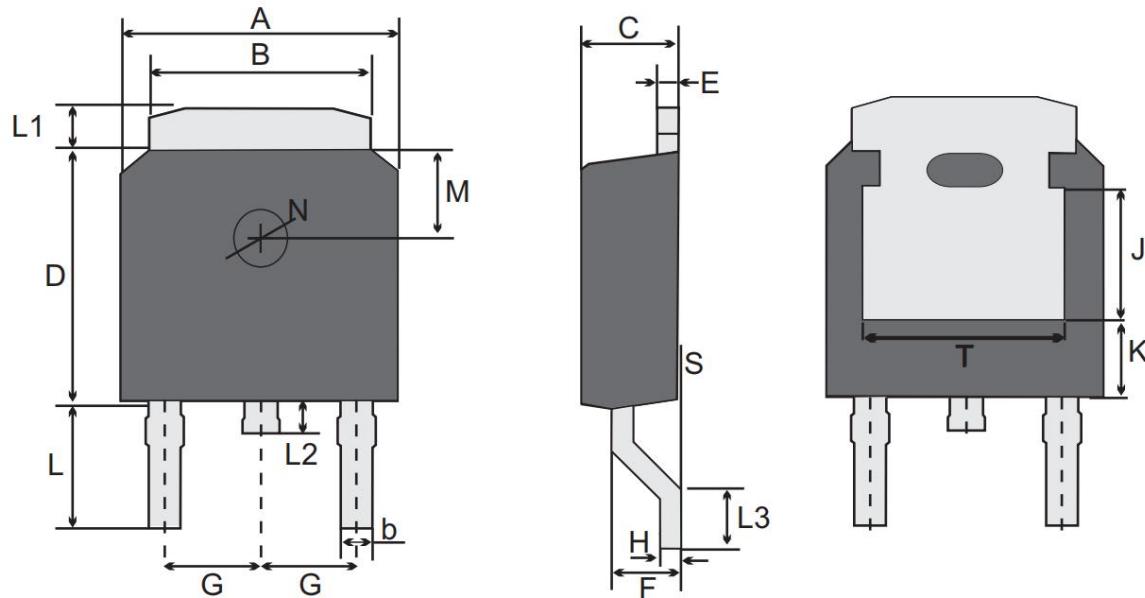


Fig.12 Max. Transient Thermal Impedance



TO-252AB Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	6.300	6.700	0.248	0.264
B	5.130	5.530	0.202	0.218
b	0.660	0.860	0.026	0.034
C	2.100	2.500	0.083	0.098
D	5.900	6.300	0.232	0.248
E	0.410	0.610	0.016	0.024
F	1.270	1.870	0.050	0.074
G	2.300 TYP.		0.091 TYP.	
H	0.450	0.550	0.018	0.022
L	2.600	3.000	0.102	0.118
L1	0.800	1.200	0.031	0.047
L2	0.600	1.000	0.024	0.039
L3	1.000	1.750	0.039	0.069
S	0.000	0.230	0.000	0.009
M	1.800 TYP.		0.071 TYP.	
N	1.300 TYP.		0.051 TYP.	
J	3.200 REF		0.126 REF	
K	1.800 REF		0.071 REF	
T	4.830 REF		0.190 REF	